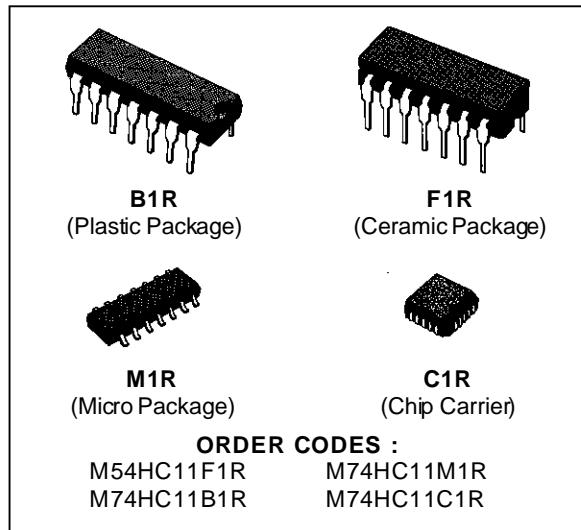


## TRIPLE 3-INPUT AND GATE

- HIGH SPEED  
 $t_{PD} = 7 \text{ ns (TYP.)}$  AT  $V_{CC} = 5 \text{ V}$
- LOW POWER DISSIPATION  
 $I_{CC} = 1 \mu\text{A (MAX.)}$  AT  $T_A = 25^\circ\text{C}$
- HIGH NOISE IMMUNITY  
 $V_{NIH} = V_{NIL} = 28 \% V_{CC}$  (MIN.)
- OUTPUT DRIVE CAPABILITY  
 10 LSTTL LOADS
- SYMMETRICAL OUTPUT IMPEDANCE  
 $|I_{OH}| = I_{OL} = 4 \text{ mA (MIN.)}$
- BALANCED PROPAGATION DELAYS  
 $t_{PLH} = t_{PHL}$
- WIDE OPERATING VOLTAGE RANGE  
 $V_{CC (\text{OPR})} = 2 \text{ V TO } 6 \text{ V}$
- PIN AND FUNCTION COMPATIBLE WITH  
 54/74LS11

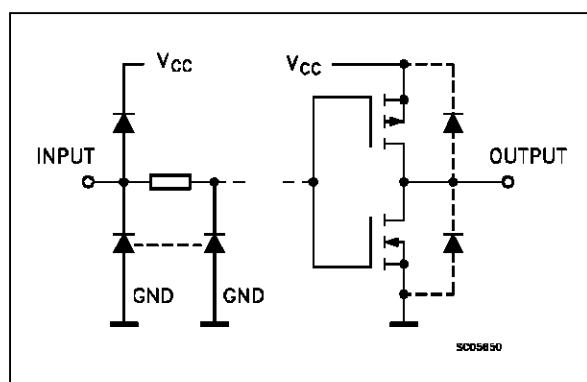


### DESCRIPTION

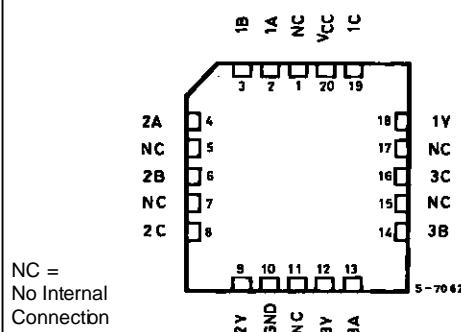
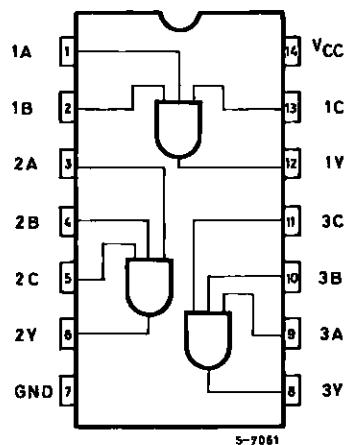
The M54/74HC11 is a high speed CMOS TRIPLE 3-INPUT AND GATE fabricated in silicon gate C<sup>2</sup>MOS technology.

It has the same high speed performance of LSTTL combined with true CMOS low power consumption. The internal circuit is composed of 4 stages including buffered output, which gives high noise immunity and a stable output. All inputs are equipped with protection circuits against static discharge and transient excess voltage.

### INPUT AND OUTPUT EQUIVALENT CIRCUIT



### PIN CONNECTIONS (top view)

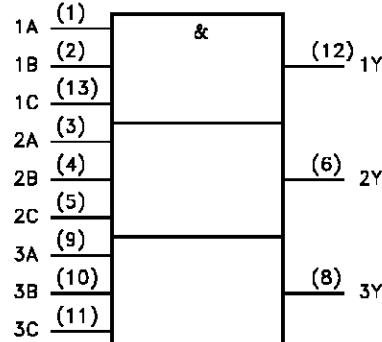


# M54/M74HC11

## TRUTH TABLE

A	B	C	Y
L	X	X	L
X	L	X	L
X	X	L	L
H	H	H	H

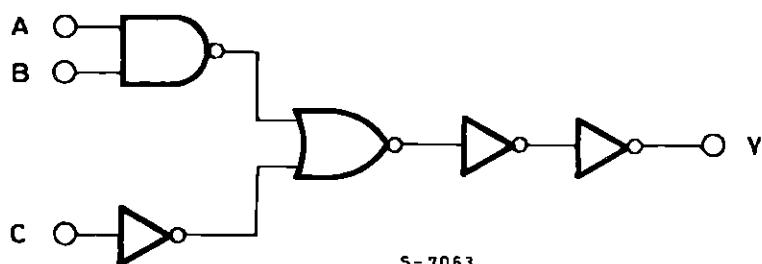
## IEC Logic Symbol



## PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
1, 3, 9	1A to 3A	Data Inputs
2, 4, 10	1B to 3B	Data Inputs
13, 5, 11	1C to 3C	Data Inputs
12, 6, 8	1Y to 3Y	Data Outputs
7	GND	Ground (0V)
14	V <sub>CC</sub>	Positive Supply Voltage

## SCHEMATIC CIRCUIT (Per Gate)



S-7063

## ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Supply Voltage	-0.5 to +7	V
V <sub>I</sub>	DC Input Voltage	-0.5 to V <sub>CC</sub> + 0.5	V
V <sub>O</sub>	DC Output Voltage	-0.5 to V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	DC Input Diode Current	± 20	mA
I <sub>OK</sub>	DC Output Diode Current	± 20	mA
I <sub>O</sub>	DC Output Source Sink Current Per Output Pin	± 25	mA
I <sub>CC</sub> or I <sub>GND</sub>	DC V <sub>CC</sub> or Ground Current	± 50	mA
P <sub>D</sub>	Power Dissipation	500 (*)	mW
T <sub>stg</sub>	Storage Temperature	-65 to +150	°C
T <sub>L</sub>	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

(\*) 500 mW:  $\leq 65^{\circ}\text{C}$  derate to 300 mW by  $10\text{mW}/^{\circ}\text{C}$ :  $65^{\circ}\text{C}$  to  $85^{\circ}\text{C}$

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value			Unit
V <sub>CC</sub>	Supply Voltage	2 to 6			V
V <sub>I</sub>	Input Voltage	0 to V <sub>CC</sub>			V
V <sub>O</sub>	Output Voltage	0 to V <sub>CC</sub>			V
T <sub>OP</sub>	Operating Temperature: M54HC Series M74HC Series	-55 to +125 -40 to +85			°C °C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time	V <sub>CC</sub> = 2 V	0 to 1000		
		V <sub>CC</sub> = 4.5 V	0 to 500		
		V <sub>CC</sub> = 6 V	0 to 400		

## DC SPECIFICATIONS

Symbol	Parameter	Test Conditions		Value						Unit	
		V <sub>CC</sub> (V)		T <sub>A</sub> = 25 °C 54HC and 74HC			-40 to 85 °C 74HC		-55 to 125 °C 54HC		
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
V <sub>IH</sub>	High Level Input Voltage	2.0		1.5			1.5		1.5		V
		4.5		3.15			3.15		3.15		
		6.0		4.2			4.2		4.2		
V <sub>IL</sub>	Low Level Input Voltage	2.0			0.5		0.5		0.5		V
		4.5			1.35		1.35		1.35		
		6.0			1.8		1.8		1.8		
V <sub>OH</sub>	High Level Output Voltage	2.0	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>	1.9	2.0		1.9		1.9		V
		4.5		4.4	4.5		4.4		4.4		
		6.0		5.9	6.0		5.9		5.9		
		4.5	I <sub>O</sub> =-4.0 mA	4.18	4.31		4.13		4.10		
		6.0		5.68	5.8		5.63		5.60		
V <sub>OL</sub>	Low Level Output Voltage	2.0	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>		0.0	0.1		0.1		0.1	V
		4.5			0.0	0.1		0.1		0.1	
		6.0			0.0	0.1		0.1		0.1	
		4.5	I <sub>O</sub> = 4.0 mA		0.17	0.26		0.33		0.40	
		6.0			0.18	0.26		0.33		0.40	
I <sub>I</sub>	Input Leakage Current	6.0	V <sub>I</sub> = V <sub>CC</sub> or GND			±0.1		±1		±1	µA
I <sub>CC</sub>	Quiescent Supply Current	6.0	V <sub>I</sub> = V <sub>CC</sub> or GND			1		10		20	µA

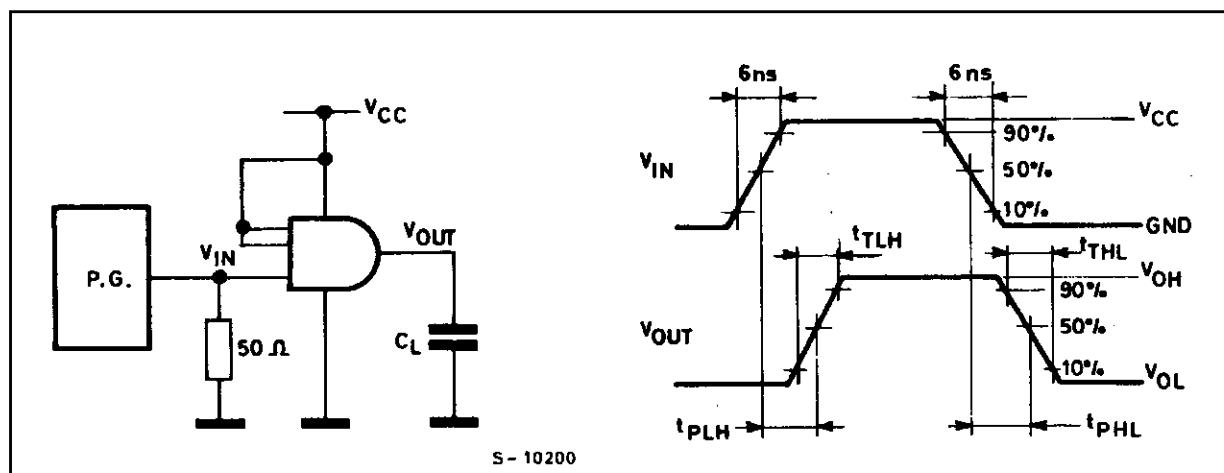
## M54/M74HC11

### AC ELECTRICAL CHARACTERISTICS ( $C_L = 50 \text{ pF}$ , Input $t_r = t_f = 6 \text{ ns}$ )

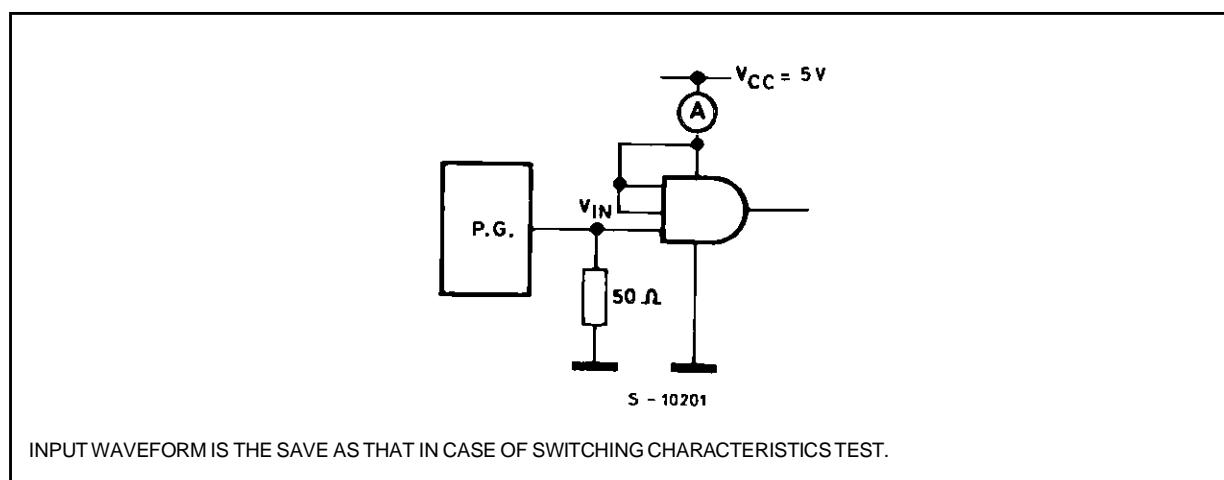
Symbol	Parameter	Test Conditions			Value						Unit
		$V_{CC}$ (V)	$T_A = 25^\circ\text{C}$ 54HC and 74HC			$-40 \text{ to } 85^\circ\text{C}$ 74HC		$-55 \text{ to } 125^\circ\text{C}$ 54HC			
			Min.	Typ.	Max.	Min.	Max.	Min.	Max.		
$t_{TLH}$ $t_{THL}$	Output Transition Time	2.0		30	75		95		110	ns	
		4.5		8	15		19		22		
		6.0		7	13		16		19		
$t_{PLH}$ $t_{PHL}$	Propagation Delay Time	2.0		40	85		105		130	ns	
		4.5		10	17		21		26		
		6.0		9	14		18		22		
$C_{IN}$	Input Capacitance			5	10		10		10	pF	
$C_{PD}$ (*)	Power Dissipation Capacitance			26						pF	

(\*)  $C_{PD}$  is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load.  
(Refer to Test Circuit). Average operating current can be obtained by the following equation.  $I_{CC(\text{opr})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/3$  (per Gate)

### SWITCHING CHARACTERISTICS TEST CIRCUIT

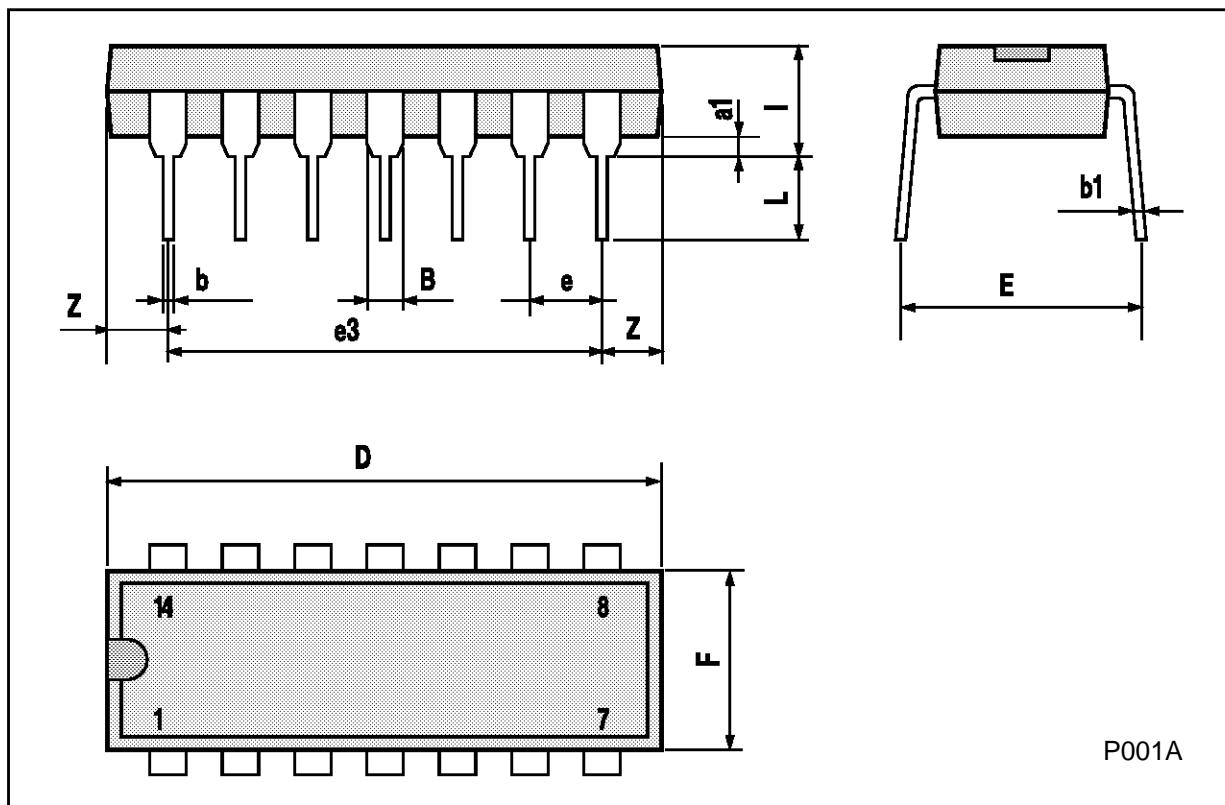


### TEST CIRCUIT $I_{CC}$ (Opr.)



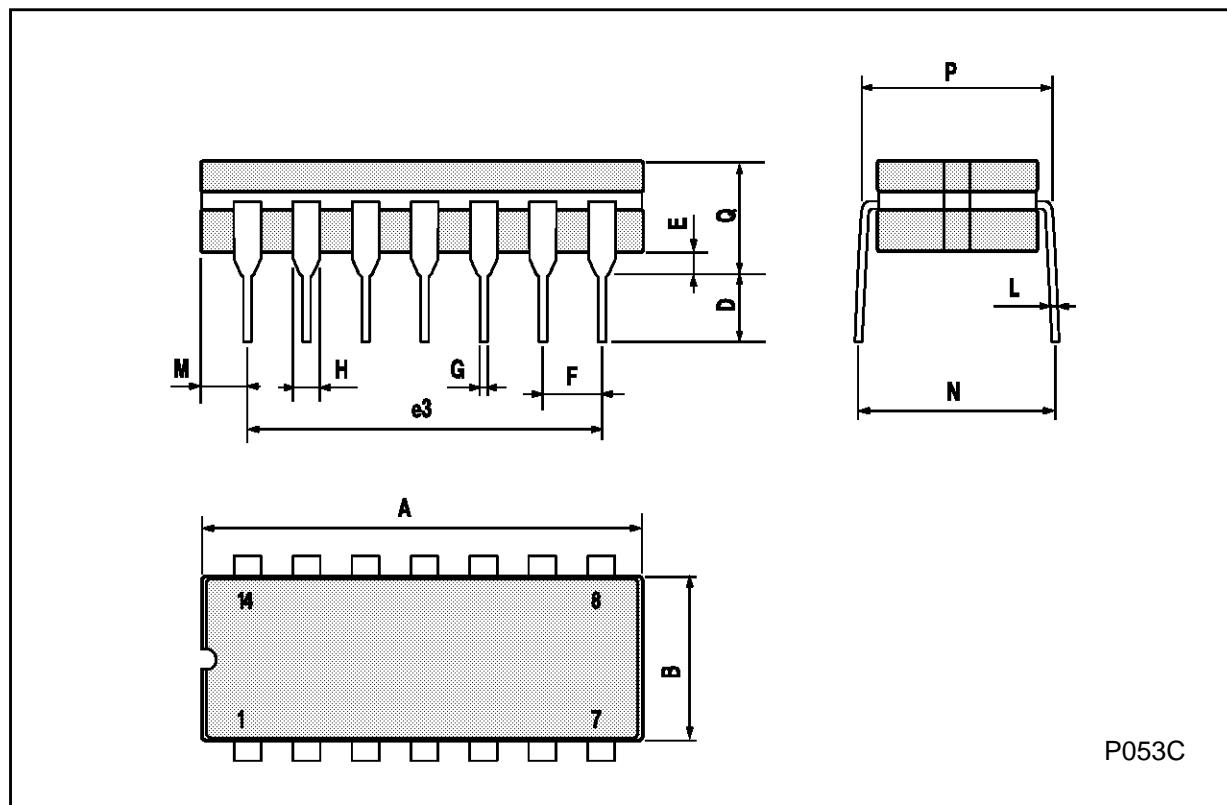
## Plastic DIP14 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100



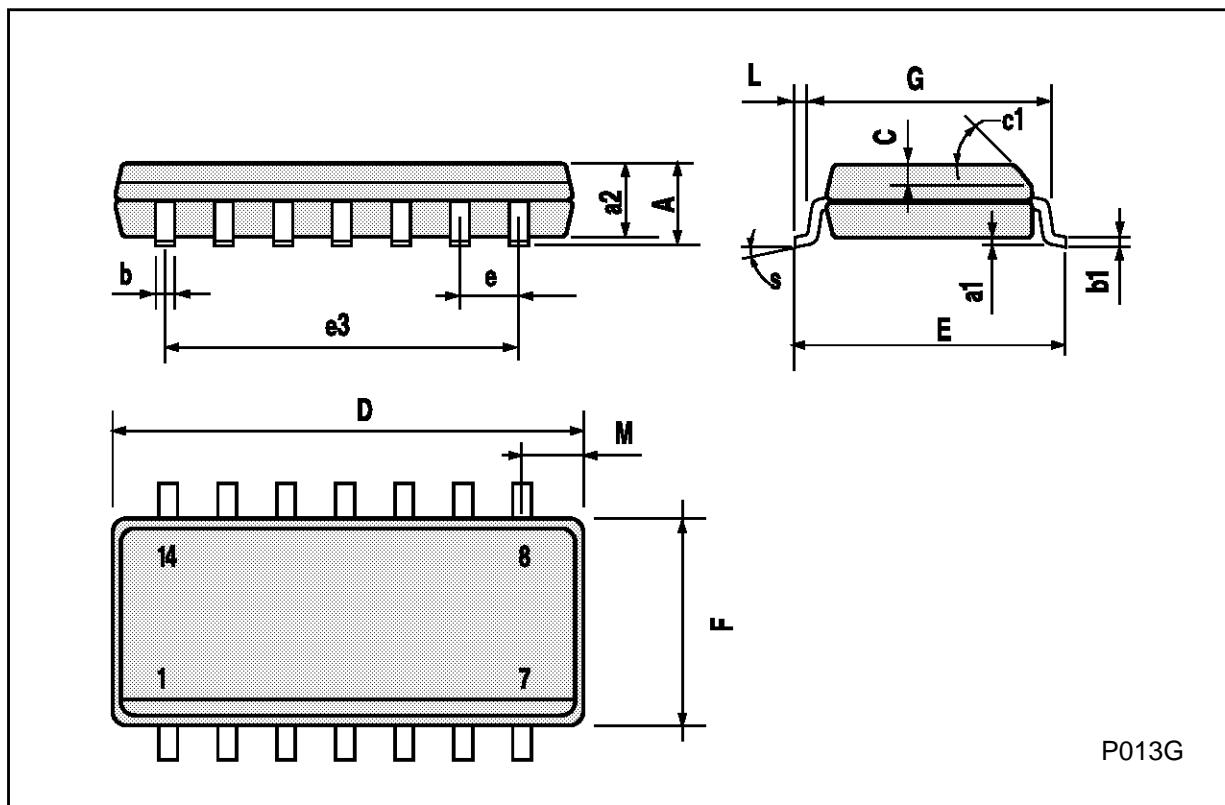
Ceramic DIP14/1 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			20			0.787
B			7.0			0.276
D		3.3			0.130	
E	0.38			0.015		
e3		15.24			0.600	
F	2.29		2.79	0.090		0.110
G	0.4		0.55	0.016		0.022
H	1.17		1.52	0.046		0.060
L	0.22		0.31	0.009		0.012
M	1.52		2.54	0.060		0.100
N			10.3			0.406
P	7.8		8.05	0.307		0.317
Q			5.08			0.200



## SO14 MECHANICAL DATA

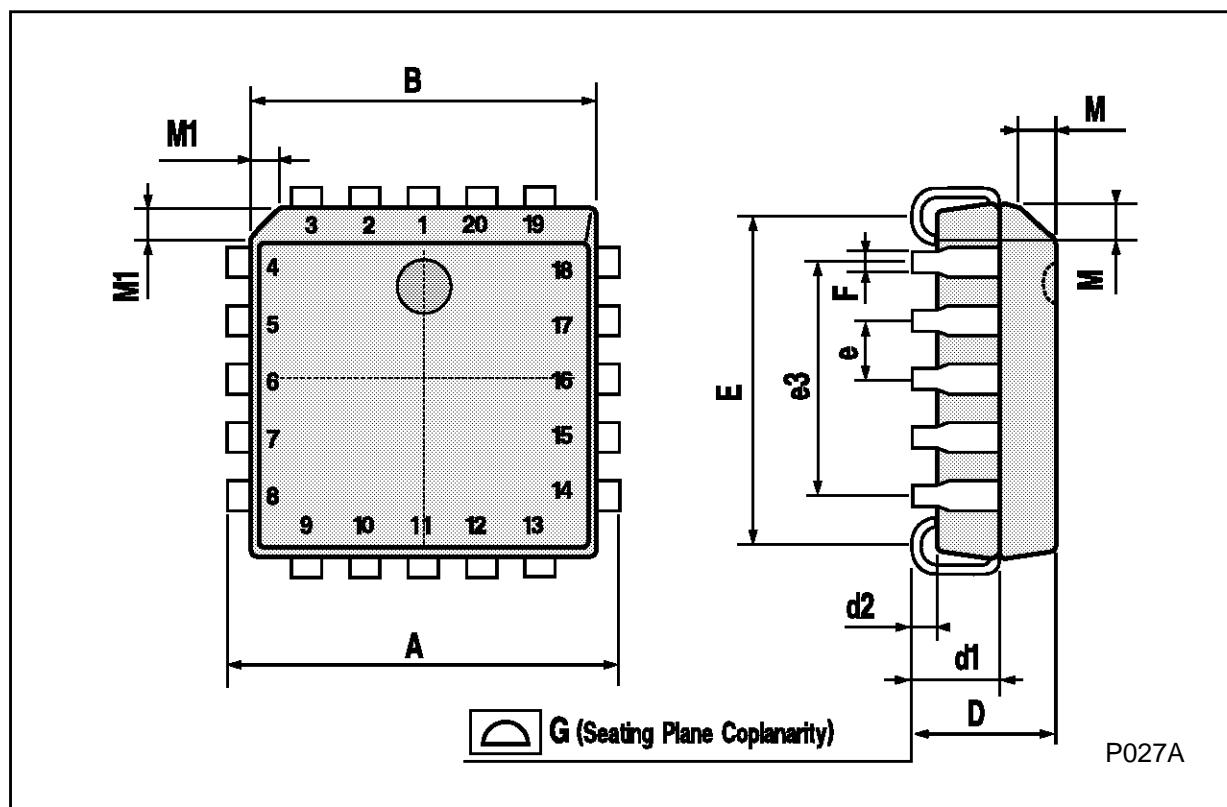
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1		45° (typ.)				
D	8.55		8.75	0.336		0.344
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.68			0.026
S		8° (max.)				



P013G

## PLCC20 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	9.78		10.03	0.385		0.395
B	8.89		9.04	0.350		0.356
D	4.2		4.57	0.165		0.180
d1		2.54			0.100	
d2		0.56			0.022	
E	7.37		8.38	0.290		0.330
e		1.27			0.050	
e3		5.08			0.200	
F		0.38			0.015	
G			0.101			0.004
M		1.27			0.050	
M1		1.14			0.045	



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